

LM4893

LM4893 1.1 Watt Audio Power Amplifier



Literature Number: SNAS159D

1.1 Watt Audio Power Amplifier

General Description

The LM4893 is an audio power amplifier primarily designed for demanding applications in mobile phones and other portable communication device applications. It is capable of delivering 1.1 watt of continuous average power to an 8Ω BTL load with less than 1% distortion (THD+N) from a 5V_{DC} power supply.

Boomer audio power amplifiers were designed specifically to provide high quality output power with a minimal amount of external components. The LM4893 does not require output coupling capacitors or bootstrap capacitors, and therefore is ideally suited for lower-power portable applications where minimal space and power consumption are primary requirements.

The LM4893 features a low-power consumption global shutdown mode, which is achieved by driving the shutdown pin with logic low. Additionally, the LM4893 features an internal thermal shutdown protection mechanism.

The LM4893 contains advanced pop & click circuitry which eliminates noises which would otherwise occur during turn-on and turn-off transitions.

The LM4893 is unity-gain stable and can be configured by external gain-setting resistors.

Key Specifications

- Improved PSRR at 5V, 3V, & 217Hz 62dB (typ)
- Higher Power Output at 5V & 1% THD 1.1W (typ)
- Higher Power Output at 3V & 1% THD 350mW (typ)
- Shutdown Current 0.1μA (typ)

Features

- No output coupling capacitors, snubber networks or bootstrap capacitors required
- Unity gain stable
- Ultra low current shutdown mode
- Instantaneous turn-on time
- BTL output can drive capacitive loads up to 100pF
- Advanced pop & click circuitry eliminates noises during turn-on and turn-off transitions
- 2.2V - 5.5V operation
- Available in space-saving μSMD, SO, and MSOP packages

Applications

- Mobile Phones
- PDAs
- Portable electronic devices

Typical Application

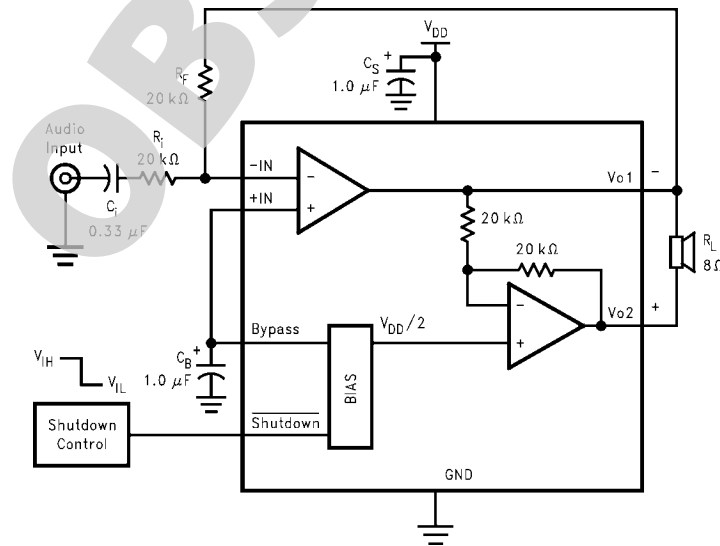
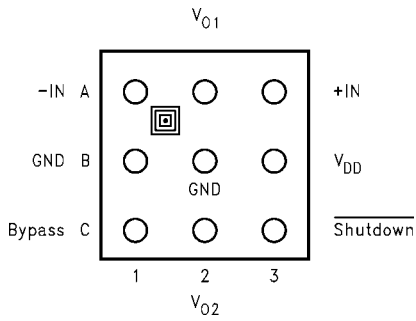


FIGURE 1. Typical Audio Amplifier Application Circuit

Connection Diagrams

9 Bump micro SMD

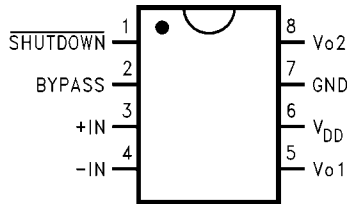


20038086

Top View

Order Number LM4893ITL, LM4893ITLX
See NS Package Number TLA09AAA

Small Outline (SO) Package

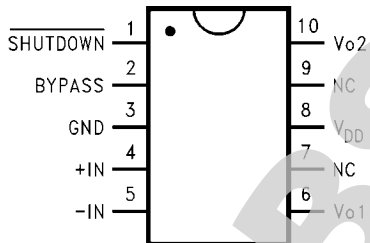


20038091

Top View

Order Number LM4893MA
See NS package Number M08A

Mini Small Outline (MSOP) Package

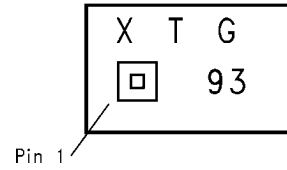


20038084

Top View

NC = No Connect
Order Number LM4893MM
See NS Package Number MUB10A

9 Bump micro SMD Marking

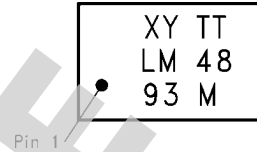


20038087

Top View

X - Date Code
T - Die Traceability
G - Boomer Family
93 - LM4893ITL

SO Marking

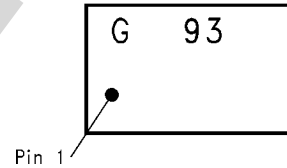


20038092

Top View

XY - Date Code
TT - Die Traceability
Bottom 2 lines - Part Number

MSOP Marking



20038085

Top View

G - Boomer Family
93 - LM4893MM

Absolute Maximum Ratings (Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (Note 9)	6.0V
Storage Temperature	-65°C to +150°C
Input Voltage	-0.3V to $V_{DD} + 0.3V$
Power Dissipation (Note 3)	Internally Limited
ESD Susceptibility (Note 4)	2000V
ESD Susceptibility (Note 5)	200V
Junction Temperature	150°C
Thermal Resistance	

θ_{JA} (TLA09AAA)	180°C/W (Note 10)
θ_{JC} (MUB10A)	56°C/W
θ_{JA} (MUB10A)	190°C/W
θ_{JC} (M08A)	35°C/W
θ_{JA} (M08A)	150°C/W

Operating Ratings

Temperature Range	
$T_{MIN} \leq T_A \leq T_{MAX}$	-40°C $\leq T_A \leq$ 85°C
Supply Voltage	2.2V $\leq V_{DD} \leq$ 5.5V

Electrical Characteristics $V_{DD} = 5V$ (Note 1, Note 2)

The following specifications apply for the circuit shown in Figure 1 unless otherwise specified. Limits apply for $T_A = 25^\circ\text{C}$.

Symbol	Parameter	Conditions	LM4893		Units (Limits)
			Typical (Note 6)	Limit (Note 7) (Note 8)	
I_{DD}	Quiescent Power Supply Current	$V_{IN} = 0V$, 8 Ω BTL	5	10	mA (max)
I_{SD}	Shutdown Current	$V_{shutdown} = GND$	0.1	2.0	μA (max)
V_{OS}	Output Offset Voltage		5	40	mV (max)
P_o	Output Power	THD = 1% (max); $f = 1\text{kHz}$	1.1	0.9	W (min)
THD+N	Total Harmonic Distortion+Noise	$P_o = 0.4W_{rms}$; $f = 1\text{kHz}$	0.1		%
PSRR	Power Supply Rejection Ratio	$V_{ripple} = 200\text{mVsine p-p}$, $C_B = 1.0\mu\text{F}$ Input terminated with 10 Ω to ground	68 ($f = 1\text{kHz}$) 62 ($f = 217\text{Hz}$)	55	dB (min)
V_{SDIH}	Shutdown High Input Voltage			1.4	V (min)
V_{SDIL}	Shutdown Low Input Voltage			0.4	V (max)
N_{OUT}	Output Noise	A-Weighted; Measured across 8 Ω BTL Input terminated with 10 Ω to ground	26		μV_{RMS}

Electrical Characteristics $V_{DD} = 3.0V$ (Note 1, Note 2)

The following specifications apply for the circuit shown in Figure 1 unless otherwise specified. Limits apply for $T_A = 25^\circ\text{C}$.

Symbol	Parameter	Conditions	LM4893		Units (Limits)
			Typical (Note 6)	Limit (Note 7) (Note 8)	
I_{DD}	Quiescent Power Supply Current	$V_{IN} = 0V$, 8 Ω BTL	4.5	9	mA (max)
I_{SD}	Shutdown Current	$V_{shutdown} = GND$	0.1	2.0	μA (max)
V_{OS}	Output Offset Voltage		5	40	mV (max)
P_o	Output Power	THD = 1% (max); $f = 1\text{kHz}$	350	320	mW
THD+N	Total Harmonic Distortion+Noise	$P_o = 0.15W_{rms}$; $f = 1\text{kHz}$	0.1		%
PSRR	Power Supply Rejection Ratio	$V_{ripple} = 200\text{mVsine p-p}$, $C_B = 1.0\mu\text{F}$ Input terminated with 10 Ω to ground	68 ($f = 1\text{kHz}$) 62 ($f = 217\text{Hz}$)	55	dB (min)
V_{SDIH}	Shutdown High Input Voltage			1.4	V (min)
V_{SDIL}	Shutdown Low Input Voltage			0.4	V (max)
N_{OUT}	Output Noise	A-Weighted; Measured across 8 Ω BTL Input terminated with 10 Ω to ground	26		μV_{RMS}

Electrical Characteristics $V_{DD} = 2.6V$ (Note 1, Note 2)

The following specifications apply for the circuit shown in Figure 1 unless otherwise specified. Limits apply for $T_A = 25^\circ C$.

Symbol	Parameter	Conditions	LM4893		Units (Limits)
			Typical	Limit	
			(Note 6)	(Note 7) (Note 8)	
I_{DD}	Quiescent Power Supply Current	$V_{IN} = 0V, 8\Omega$ BTL	3.5		mA
I_{SD}	Shutdown Current	$V_{shutdown} = GND$	0.1		μA
V_{OS}	Output Offset Voltage		5		mV
P_o	Output Power	THD = 1% (max); f = 1kHz			mW
		$R_L = 8\Omega$	250		
		$R_L = 4\Omega$	350		
THD+N	Total Harmonic Distortion+Noise	$P_o = 0.1W_{rms}; f = 1kHz$	0.1		%
PSRR	Power Supply Rejection Ratio	$V_{ripple} = 200mV_{sine}$ p-p, $C_B = 1.0\mu F$ Input terminated with 10Ω to ground	55 (f = 1kHz) 55 (f = 217Hz)		dB

Note 1: All voltages are measured with respect to the ground pin, unless otherwise specified.

Note 2: *Absolute Maximum Ratings* indicate limits beyond which damage to the device may occur. *Operating Ratings* indicate conditions for which the device is functional, but do not guarantee specific performance limits. *Electrical Characteristics* state DC and AC electrical specifications under particular test conditions which guarantee specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not guaranteed for parameters where no limit is given, however, the typical value is a good indication of device performance.

Note 3: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{JMAX}, θ_{JA} , and the ambient temperature T_A . The maximum allowable power dissipation is $P_{DMAX} = (T_{JMAX} - T_A) / \theta_{JA}$ or the number given in Absolute Maximum Ratings, whichever is lower. For the LM4893, see power derating curves for additional information.

Note 4: Human body model, 100 pF discharged through a 1.5 k Ω resistor.

Note 5: Machine Model, 220pF–240pF discharged through all pins.

Note 6: Typical values are measured at 25°C and represent the parametric norm.

Note 7: Limits are guaranteed to National's AOQL (Average Outgoing Quality Level).

Note 8: For micro SMD only, shutdown current is measured in a Normal Room Environment. Exposure to direct sunlight will increase I_{SD} by a maximum of 2 μA .

Note 9: If the product is in shutdown mode, and V_{DD} exceeds 6V (to a max of 8V V_{DD}), then most of the excess current will flow through the ESD protection circuits. If the source impedance limits the current to a max of 10mA, then the part will be protected. If the part is enabled when V_{DD} is above 6V, circuit performance will be curtailed or the part may be permanently damaged.

Note 10: All bumps have the same thermal resistance and contribute equally when used to lower thermal resistance.

Note 11: Maximum power dissipation (P_{DMAX}) in the device occurs at an output power level significantly below full output power. P_{DMAX} can be calculated using Equation 1 shown in the Application section. It may also be obtained from the power dissipation graphs.

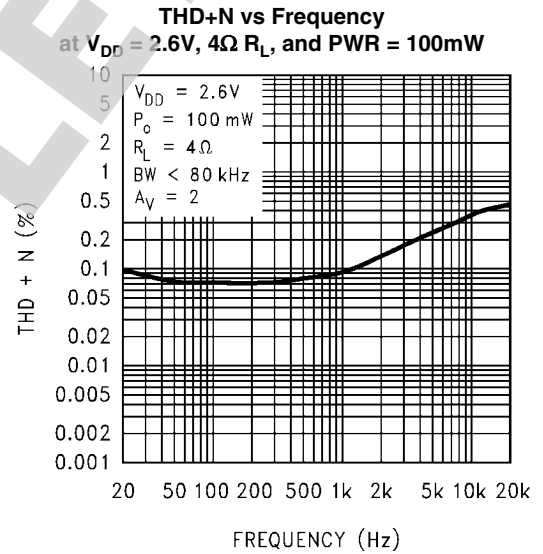
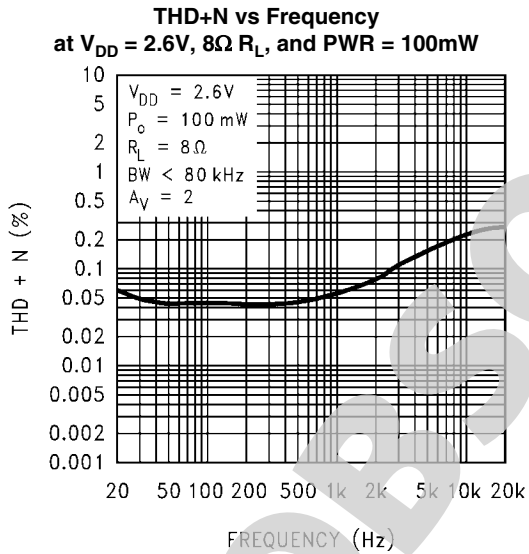
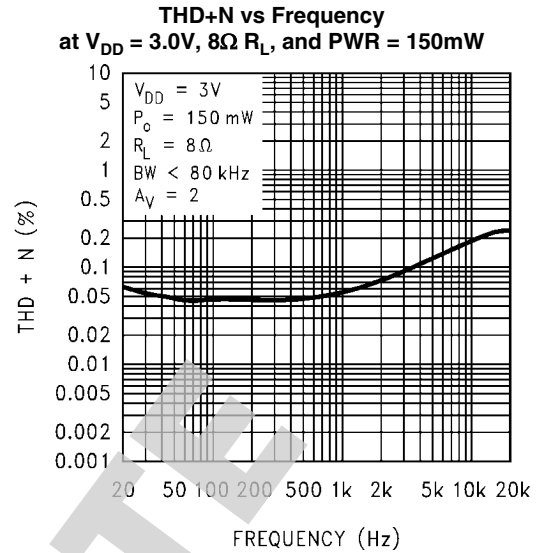
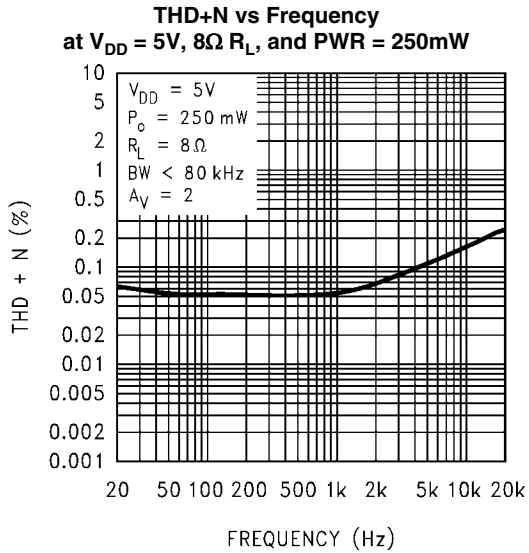
External Components Description

(Figure 1)

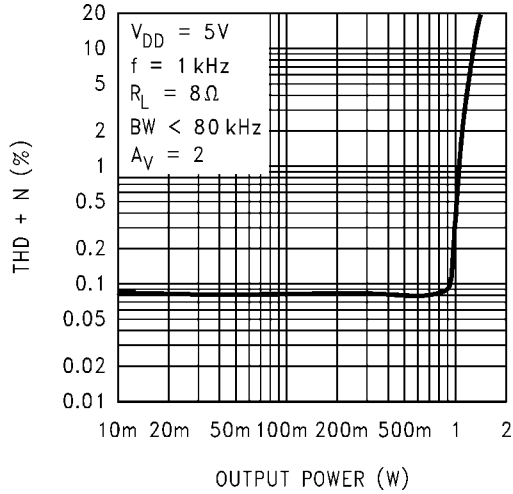
Components		Functional Description
1.	R_i	Inverting input resistance which sets the closed-loop gain in conjunction with R_f . This resistor also forms a high pass filter with C_i at $f_c = 1/(2\pi R_i C_i)$.
2.	C_i	Input coupling capacitor which blocks the DC voltage at the amplifiers input terminals. Also creates a highpass filter with R_i at $f_c = 1/(2\pi R_i C_i)$. Refer to the section, Proper Selection of External Components , for an explanation of how to determine the value of C_i .
3.	R_f	Feedback resistance which sets the closed-loop gain in conjunction with R_i .
4.	C_S	Supply bypass capacitor which provides power supply filtering. Refer to the Power Supply Bypassing section for information concerning proper placement and selection of the supply bypass capacitor.
5.	C_B	Bypass pin capacitor which provides half-supply filtering. Refer to the section, Proper Selection of External Components , for information concerning proper placement and selection of C_B .

OBSOLETE

Typical Performance Characteristics

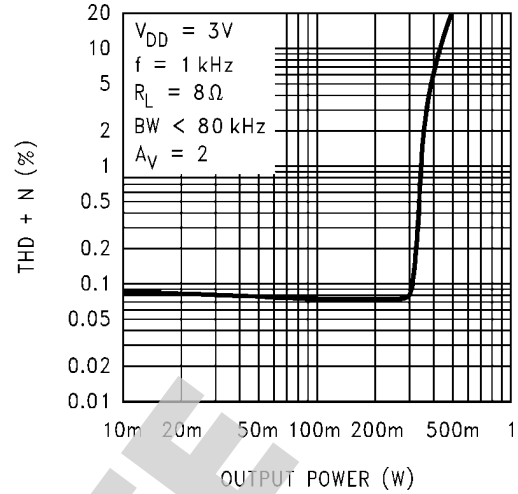


THD+N vs Power Out
 @ $V_{DD} = 5V$, $8\Omega R_L$, $1kHz$



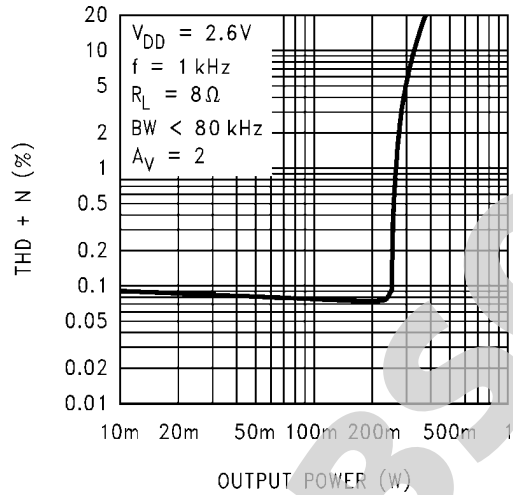
20038041

THD+N vs Power Out
 @ $V_{DD} = 3.0V$, $8\Omega R_L$, $1kHz$



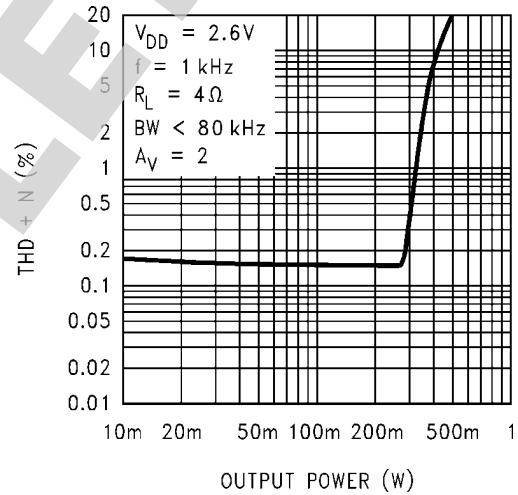
20038042

THD+N vs Power Out
 @ $V_{DD} = 2.6V$, $8\Omega R_L$, $1kHz$



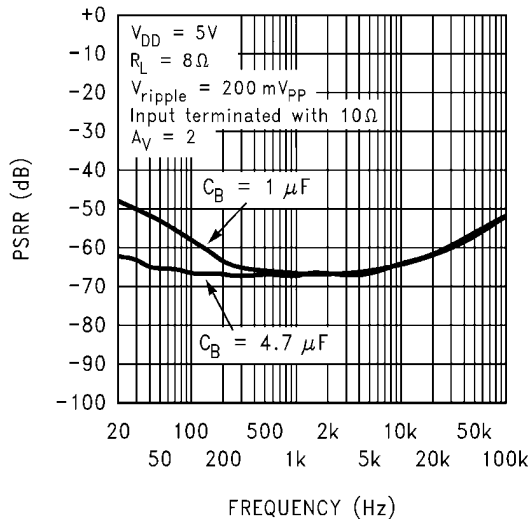
20038043

THD+N vs Power Out
 @ $V_{DD} = 2.6V$, $4\Omega R_L$, $1kHz$



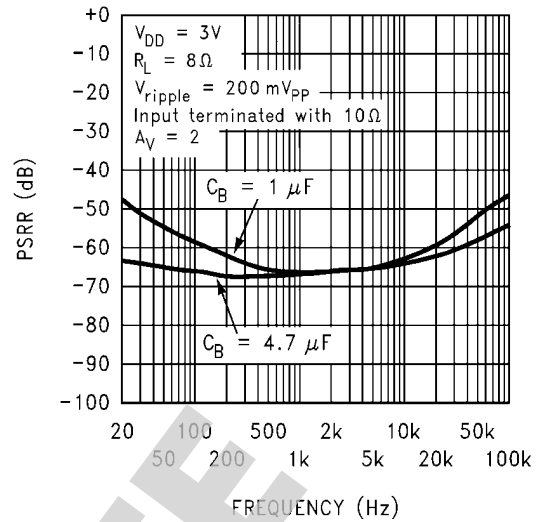
20038044

Power Supply Rejection Ratio (PSRR) @ $V_{DD} = 5V$



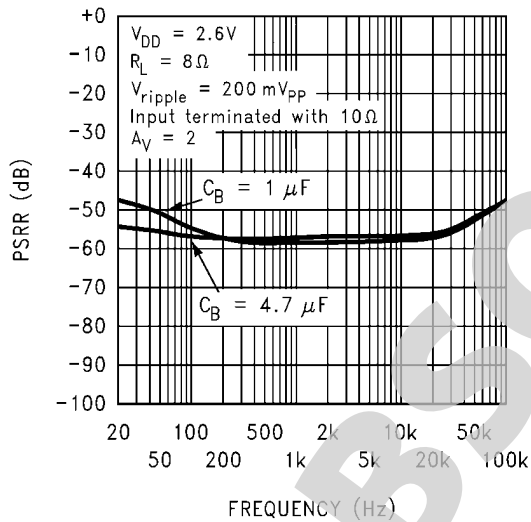
Input terminated with 10Ω R

Power Supply Rejection Ratio (PSRR) @ $V_{DD} = 3V$



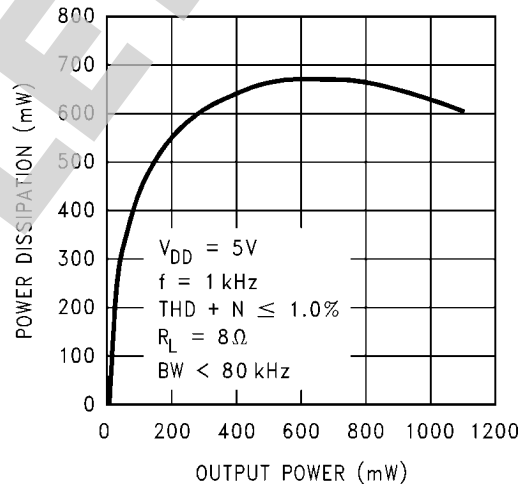
Input terminated with 10Ω R

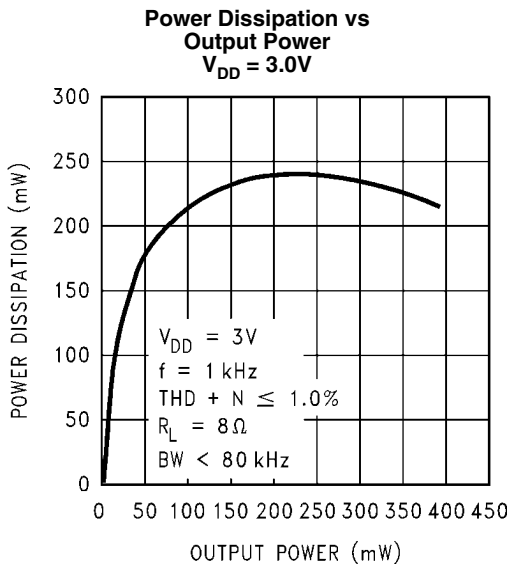
Power Supply Rejection Ratio (PSRR) @ $V_{DD} = 2.6V$



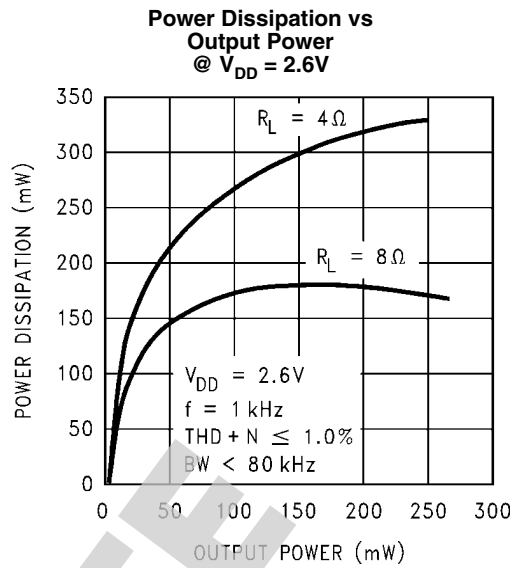
Input terminated with 10Ω R

Power Dissipation vs Output Power @ $V_{DD} = 5V$

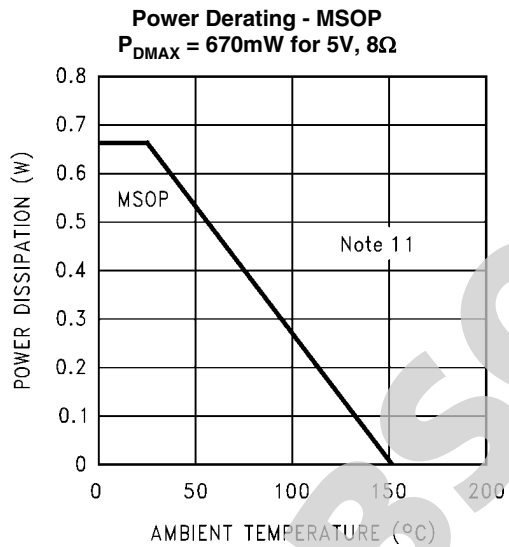




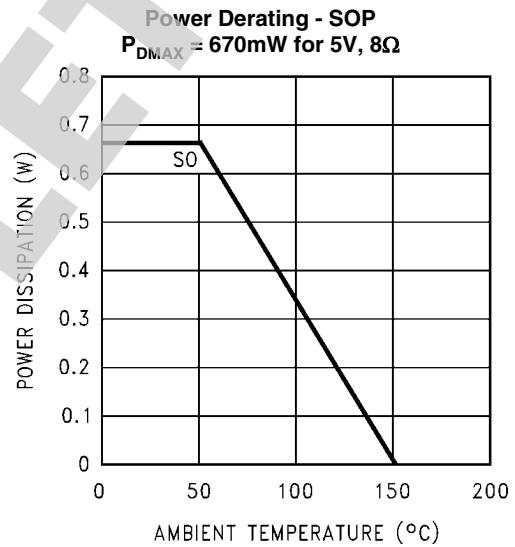
20038049



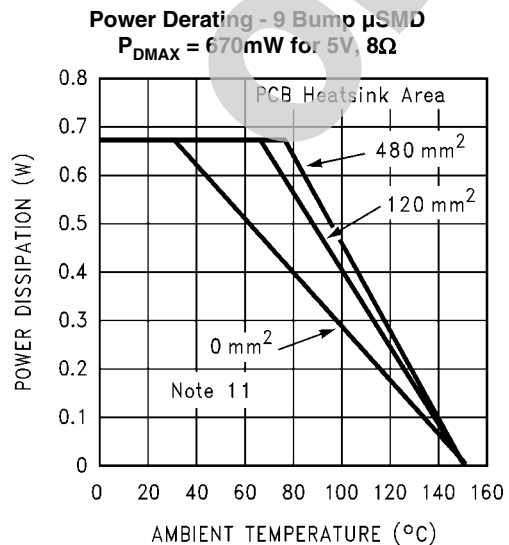
20038048



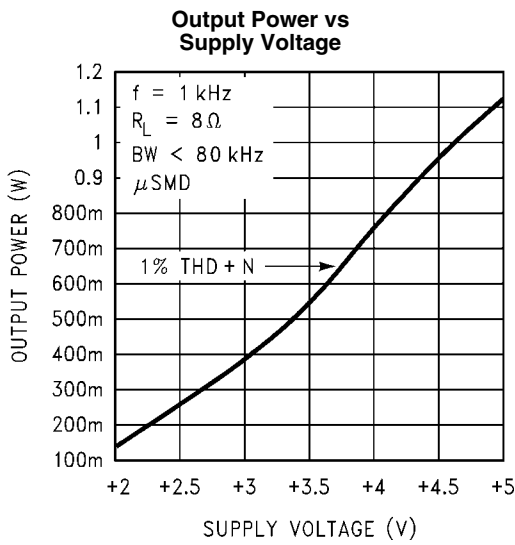
20038079



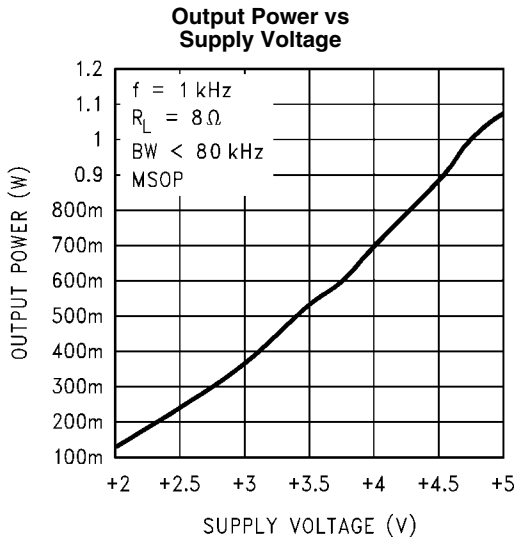
20038093



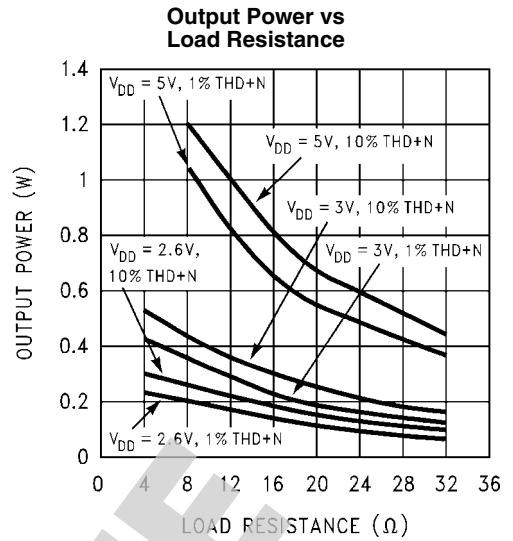
20038081



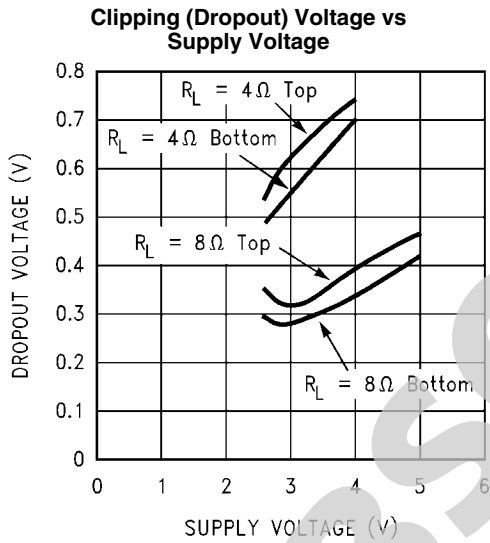
20038051



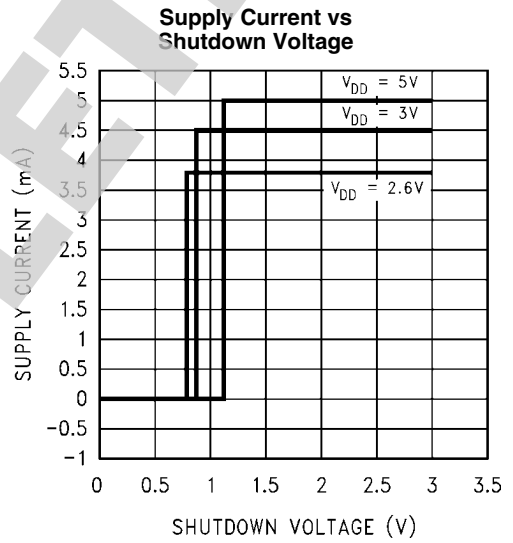
20038050



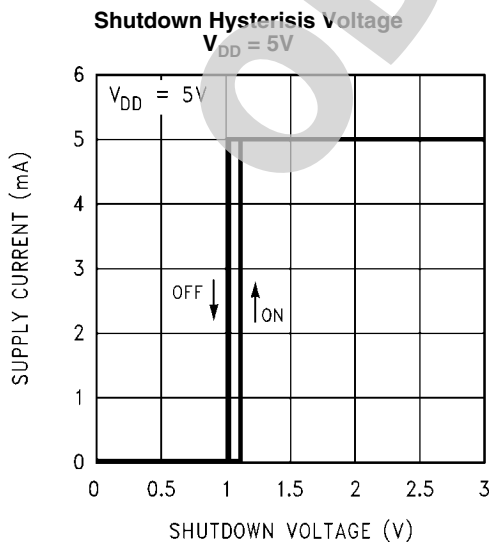
20038074



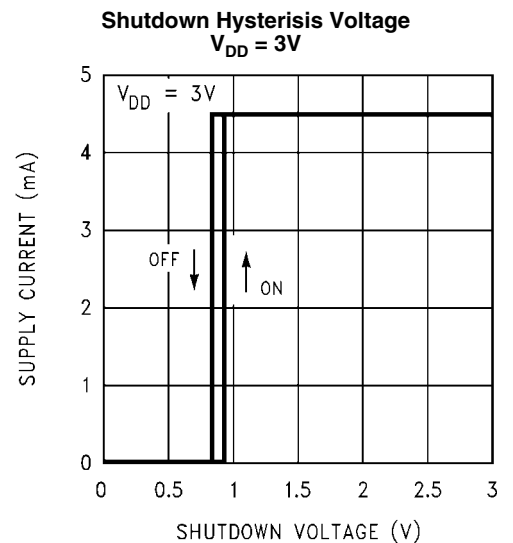
20038052



20038075

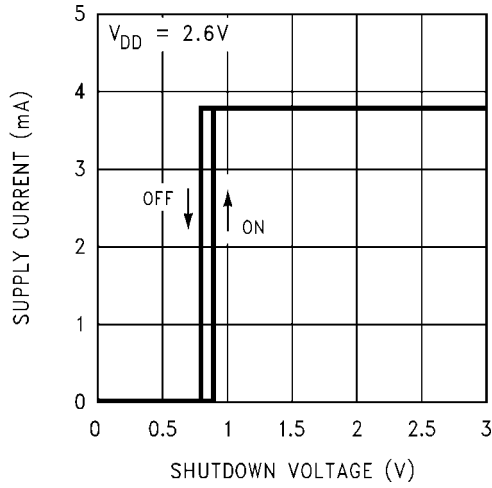


20038076



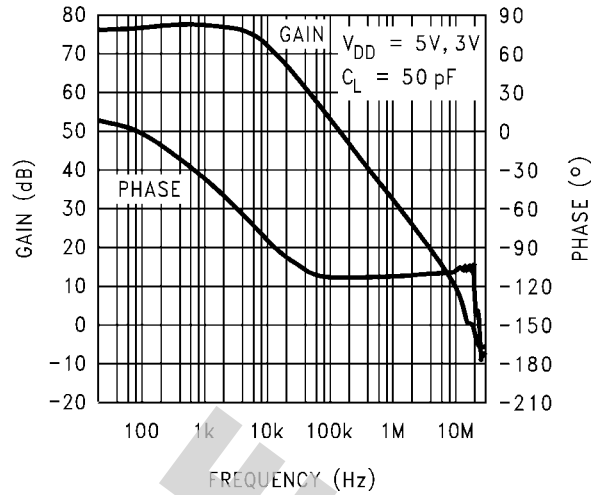
20038077

Shutdown Hysteresis Voltage
 $V_{DD} = 2.6V$



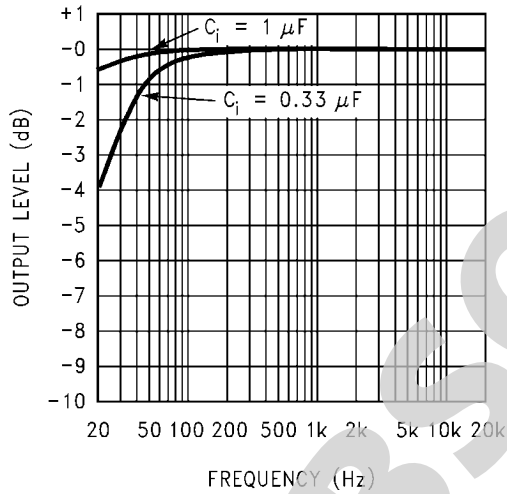
20038078

Open Loop Frequency Response



20038054

Frequency Response vs Input Capacitor Size



20038056

Application Information

BRIDGE CONFIGURATION EXPLANATION

As shown in *Figure 1*, the LM4893 has two operational amplifiers internally, allowing for a few different amplifier configurations. The first amplifier's gain is externally configurable, while the second amplifier is internally fixed in a unity-gain, inverting configuration. The closed-loop gain of the first amplifier is set by selecting the ratio of R_f to R_i , while the second amplifier's gain is fixed by the two internal 20 k Ω resistors. *Figure 1* shows that the output of amplifier one serves as the input to amplifier two which results in both amplifiers producing signals identical in magnitude, but out of phase by 180°. Consequently, the differential gain for the IC is

$$A_{VD} = 2 * (R_f/R_i)$$

By driving the load differentially through outputs Vo1 and Vo2, an amplifier configuration commonly referred to as "bridged mode" is established. Bridged mode operation is different from the classical single-ended amplifier configuration where one side of the load is connected to ground.

A bridge amplifier design has a few distinct advantages over the single-ended configuration, as it provides differential drive to the load, thus doubling output swing for a specified supply voltage. Four times the output power is possible as compared to a single-ended amplifier under the same conditions. This increase in attainable output power assumes that the amplifier is not current limited or clipped. In order to choose an amplifier's closed-loop gain without causing excessive clipping, please refer to the **Audio Power Amplifier Design** section.

A bridge configuration, such as the one used in LM4893, also creates a second advantage over single-ended amplifiers. Since the differential outputs, Vo1 and Vo2, are biased at half-supply, no net DC voltage exists across the load. This eliminates the need for an output coupling capacitor which is required in a single supply, single-ended amplifier configuration. Without an output coupling capacitor, the half-supply bias across the load would result in both increased internal IC power dissipation and also possible loudspeaker damage.

POWER DISSIPATION

Power dissipation is a major concern when designing a successful amplifier, whether the amplifier is bridged or single-ended. A direct consequence of the increased power delivered to the load by a bridge amplifier is an increase in internal power dissipation. Since the LM4893 has two operational amplifiers in one package, the maximum internal power dissipation is 4 times that of a single-ended amplifier. The maximum power dissipation for a given application can be derived from the power dissipation graphs or from Equation 1.

$$P_{DMAX} = 4 * (V_{DD})^2 / (2\pi^2 R_L) \quad (1)$$

It is critical that the maximum junction temperature (T_{JMAX}) of 150°C is not exceeded. T_{JMAX} can be determined from the power derating curves by using P_{DMAX} and the PC board foil area. By adding additional copper foil, the thermal resistance of the application can be reduced from a free air value of 150° C/W, resulting in higher P_{DMAX} . Additional copper foil can be added to any of the leads connected to the LM4893. It is especially effective when connected to V_{DD} , GND, and the output pins. Refer to the application information on the LM4893 reference design board for an example of good heat sinking. If T_{JMAX} still exceeds 150°C, then additional changes must be made. These changes can include reduced supply

voltage, higher load impedance, or reduced ambient temperature. Internal power dissipation is a function of output power. Refer to the **Typical Performance Characteristics** curves for power dissipation information for different output powers and output loading.

POWER SUPPLY BYPASSING

As with any amplifier, proper supply bypassing is critical for low noise performance and high power supply rejection. The capacitor location on both the bypass and power supply pins should be as close to the device as possible. Typical applications employ a 5V regulator with 10 μ F tantalum or electrolytic capacitor and a ceramic bypass capacitor which aid in supply stability. This does not eliminate the need for bypassing the supply nodes of the LM4893. The selection of a bypass capacitor, especially C_B , is dependent upon PSRR requirements, click and pop performance (as explained in the section, **Proper Selection of External Components**), system cost, and size constraints.

SHUTDOWN FUNCTION

In order to reduce power consumption while not in use, the LM4893 contains a SHUTDOWN pin to externally turn off the amplifier's bias circuitry. This shutdown feature turns the amplifier off when a logic low is placed on the SHUTDOWN pin. By switching the SHUTDOWN pin to ground, the LM4893 supply current draw will be minimized in idle mode. While the device will be disabled with SHUTDOWN pin voltages less than 0.4V_{DC}, the idle current may be greater than the typical value of 0.1 μ A. (Idle current is measured with the SHUTDOWN pin tied to ground).

In many applications, a microcontroller or microprocessor output is used to control the shutdown circuitry to provide a quick, smooth transition into shutdown. Another solution is to use a single-pole, single-throw switch in conjunction with an external pull-up resistor. When the switch is closed, the SHUTDOWN pin is connected to ground which disables the amplifier. If the switch is open, then the external pull-up resistor to V_{DD} will enable the LM4893. This scheme guarantees that the SHUTDOWN pin will not float thus preventing unwanted state changes.

PROPER SELECTION OF EXTERNAL COMPONENTS

Proper selection of external components in applications using integrated power amplifiers is critical to optimize device and system performance. While the LM4893 is tolerant of external component combinations, consideration to component values must be used to maximize overall system quality.

The LM4893 is unity-gain stable which gives the designer maximum system flexibility. The LM4893 should be used in low gain configurations to minimize THD+N values, and maximize the signal to noise ratio. Low gain configurations require large input signals to obtain a given output power. Input signals equal to or greater than 1 V_{rms} are available from sources such as audio codecs. Please refer to the section, **Audio Power Amplifier Design**, for a more complete explanation of proper gain selection.

Besides gain, one of the major considerations is the closed-loop bandwidth of the amplifier. To a large extent, the bandwidth is dictated by the choice of external components shown in *Figure 1*. The input coupling capacitor, C_i , forms a first order high pass filter which limits low frequency response. This value should be chosen based on needed frequency response for a few distinct reasons.

Selection Of Input Capacitor Size

Large input capacitors are both expensive and space hungry for portable designs. Clearly, a certain sized capacitor is needed to couple in low frequencies without severe attenuation. But in many cases the speakers used in portable systems, whether internal or external, have little ability to reproduce signals below 100 Hz to 150 Hz. Thus, using a large input capacitor may not increase actual system performance.

In addition to system cost and size, click and pop performance is effected by the size of the input coupling capacitor, C_i . A larger input coupling capacitor requires more charge to reach its quiescent DC voltage (nominally $1/2 V_{DD}$). This charge comes from the output via the feedback and is apt to create pops upon device enable. Thus, by minimizing the capacitor size based on necessary low frequency response, turn-on pops can be minimized.

Besides minimizing the input capacitor size, careful consideration should be paid to the bypass capacitor value. Bypass capacitor, C_B , is the most critical component to minimize turn-on pops since it determines how fast the LM4893 turns on. The slower the LM4893's outputs ramp to their quiescent DC voltage (nominally $1/2 V_{DD}$), the smaller the turn-on pop. Choosing C_B equal to $1.0 \mu\text{F}$ along with a small value of C_i (in the range of $0.1 \mu\text{F}$ to $0.39 \mu\text{F}$), should produce a virtually clickless and popless shutdown function. While the device will function properly, (no oscillations or motorboating), with C_B equal to $0.1 \mu\text{F}$, the device will be much more susceptible to turn-on clicks and pops. Thus, a value of C_B equal to $1.0 \mu\text{F}$ is recommended in all but the most cost sensitive designs.

Figure 2 shows the LM4893's turn-on characteristics when coming out of shutdown mode. Trace B is the differential output signal across a BTL 8Ω load. The LM4893's active-low SHUTDOWN pin is driven by the logic signal shown in Trace A. Trace C is the Vo1- output signal and Trace D is the Vo2+ output signal. As shown in Figure 2, the differential output signal Trace B appears just as Trace A transitions from logic low to logic high (turn-on condition).

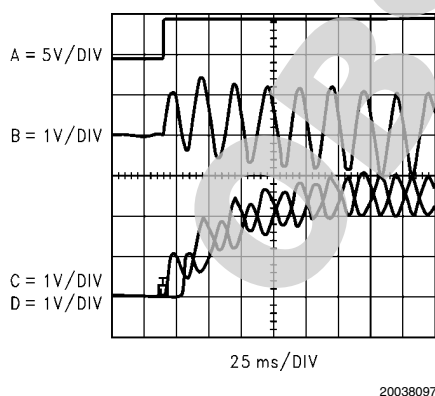


FIGURE 2. LM4893 Turn-on Characteristics
Differential output signal (Trace B) is devoid of transients. The SHUTDOWN pin is driven by a shutdown signal (Trace A). The inverting output (Trace C) and the non-inverting output (Trace D) are applied across an 8Ω BTL load.

AUDIO POWER AMPLIFIER DESIGN

A 1W/8Ω Audio Amplifier

Given:

Power Output	1 Wrms
Load Impedance	8Ω
Input Level	1 Vrms
Input Impedance	$20 \text{ k}\Omega$
Bandwidth	100 Hz–20 kHz \pm 0.25 dB

A designer must first determine the minimum supply rail to obtain the specified output power. By extrapolating from the Output Power vs Supply Voltage graphs in the **Typical Performance Characteristics** section, the supply rail can be easily found. A second way to determine the minimum supply rail is to calculate the required V_{opeak} using Equation 2 and add the output voltage. Using this method, the minimum supply voltage would be $(V_{\text{opeak}} + (V_{\text{ODTOP}} + V_{\text{ODBOT}}))$, where V_{ODBOT} and V_{ODTOP} are extrapolated from the Dropout Voltage vs Supply Voltage curve in the **Typical Performance Characteristics** section.

$$V_{\text{opeak}} = \sqrt{(2R_L P_O)} \quad (2)$$

5V is a standard voltage, in most applications, chosen for the supply rail. Extra supply voltage creates headroom that allows the LM4893 to reproduce peaks in excess of 1W without producing audible distortion. At this time, the designer must make sure that the power supply choice along with the output impedance does not violate the conditions explained in the **Power Dissipation** section.

Once the power dissipation equations have been addressed, the required differential gain can be determined from Equation 3.

$$A_{VD} \geq \sqrt{(P_O R_L)} / (V_{IN}) = V_{\text{orms}} / V_{\text{inrms}} \quad (3)$$

$$A_{VD} = (R_f / R_i)^2$$

From Equation 3, the minimum A_{VD} is 2.83; use $A_{VD} = 3$.

Since the desired input impedance was $20 \text{ k}\Omega$, and with a A_{VD} of 3, a ratio of 1.5:1 of R_f to R_i results in an allocation of $R_i = 20 \text{ k}\Omega$ and $R_f = 30 \text{ k}\Omega$. The final design step is to address the bandwidth requirements which must be stated as a pair of -3 dB frequency points. Five times away from a -3 dB point is 0.17 dB down from passband response which is better than the required $\pm 0.25 \text{ dB}$ specified.

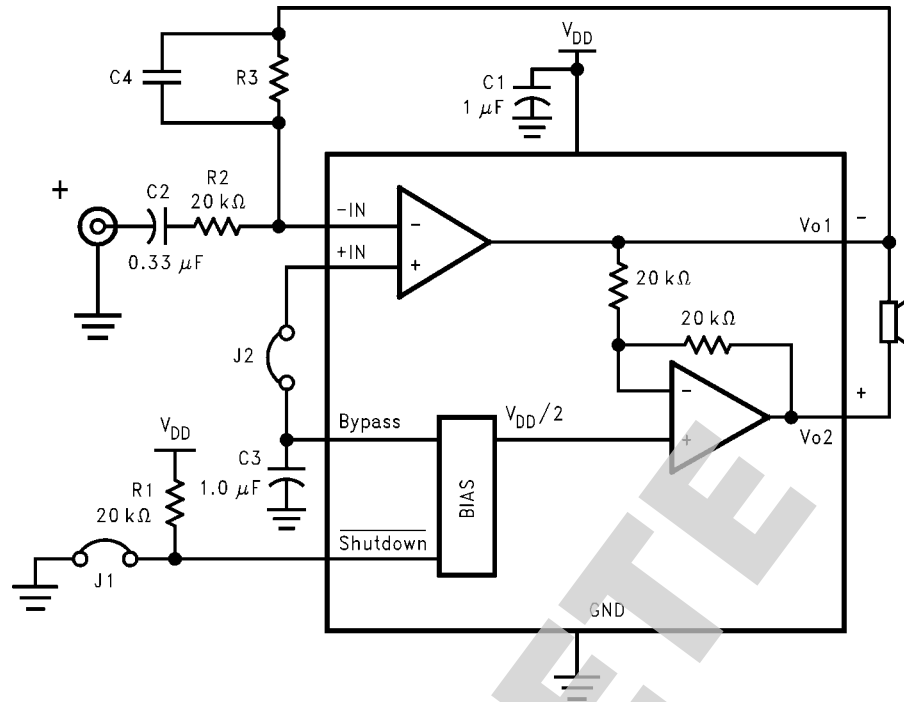
$$f_L = 100 \text{ Hz} / 5 = 20 \text{ Hz}$$

$$f_H = 20 \text{ kHz} * 5 = 100 \text{ kHz}$$

As stated in the **External Components** section, R_i in conjunction with C_i create a highpass filter.

$$C_i \geq 1 / (2\pi * 20 \text{ k}\Omega * 20 \text{ Hz}) = 0.397 \mu\text{F}; \text{ use } 0.39 \mu\text{F}$$

The high frequency pole is determined by the product of the desired frequency pole, f_H , and the differential gain, A_{VD} . With a $A_{VD} = 3$ and $f_H = 100 \text{ kHz}$, the resulting GBWP = 300 kHz which is much smaller than the LM4893 GBWP of 10 MHz . This figure displays that if a designer has a need to design an amplifier with a higher differential gain, the LM4893 can still be used without running into bandwidth limitations.

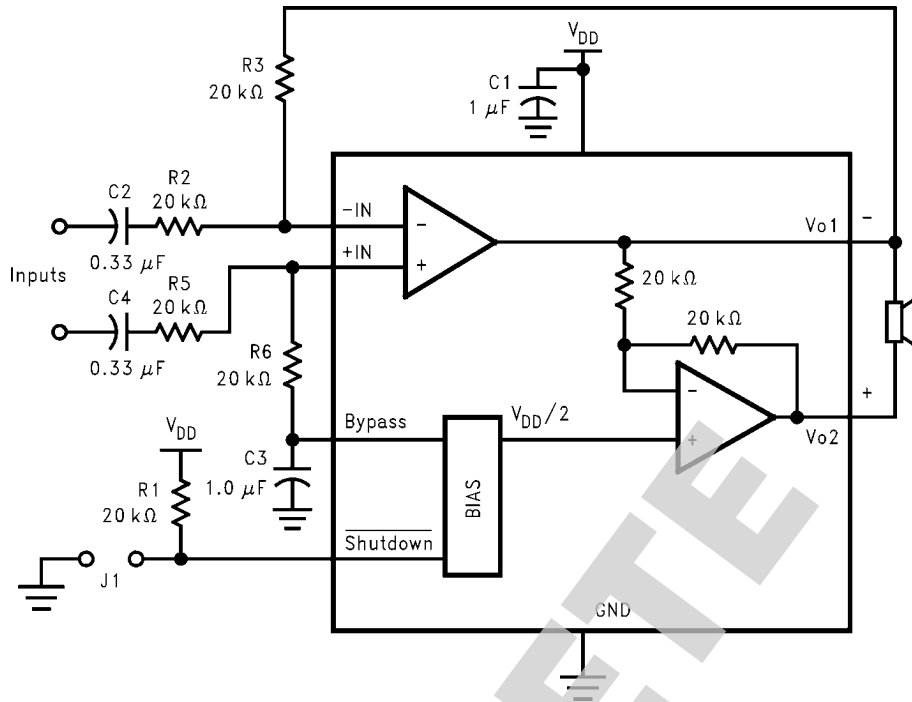


20038088

FIGURE 3. HIGHER GAIN AUDIO AMPLIFIER

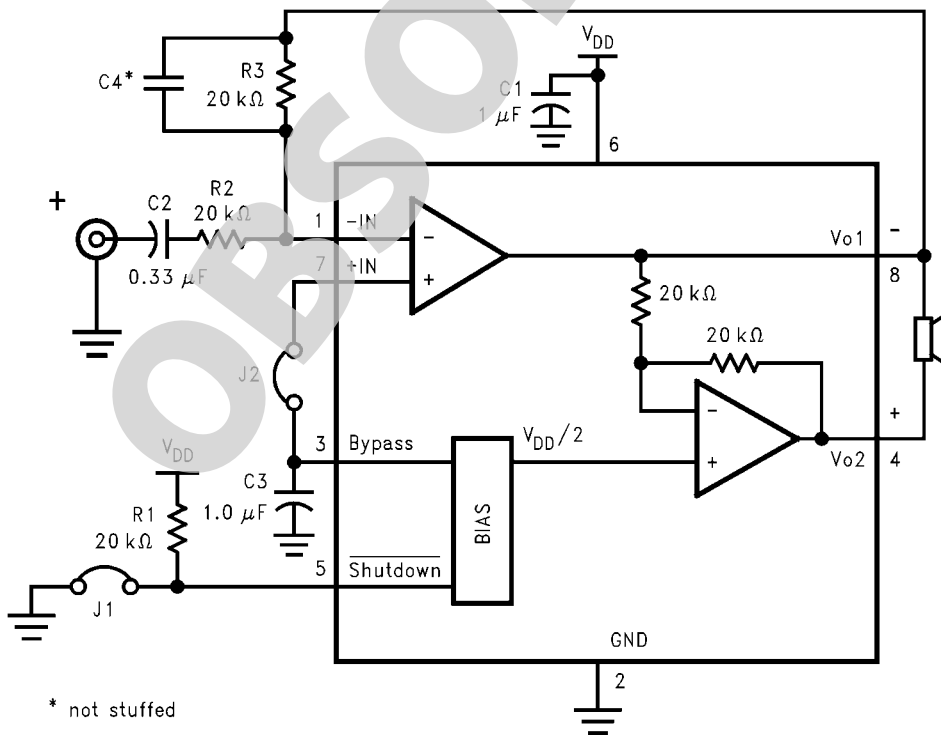
The LM4893 is unity-gain stable and requires no external components besides gain-setting resistors, an input coupling capacitor, and proper supply bypassing in the typical application. However, if a closed-loop differential gain of greater than 10 is required, a feedback capacitor (C4) may be needed as shown in Figure 2 to bandwidth limit the amplifier. This feedback capacitor creates a low pass filter that eliminates

possible high frequency oscillations. Care should be taken when calculating the -3dB frequency in that an incorrect combination of R_3 and C_4 will cause rolloff before 20kHz. A typical combination of feedback resistor and capacitor that will not produce audio band high frequency rolloff is $R_3 = 20\text{k}\Omega$ and $C_4 = 25\text{pF}$. These components result in a -3dB point of approximately 320 kHz.



20038089

FIGURE 4. DIFFERENTIAL AMPLIFIER CONFIGURATION FOR LM4893

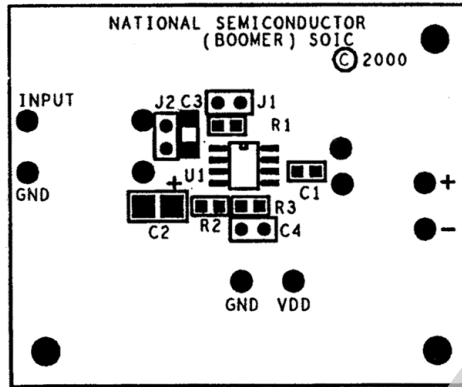


20038090

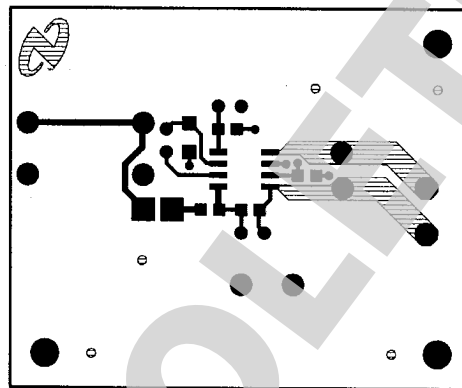
FIGURE 5. REFERENCE DESIGN BOARD and LAYOUT - micro SMD

LM4893 SO BOARD ARTWORK

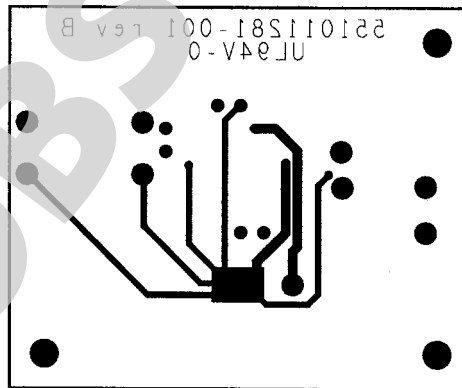
Silk Screen



Top Layer



Bottom Layer



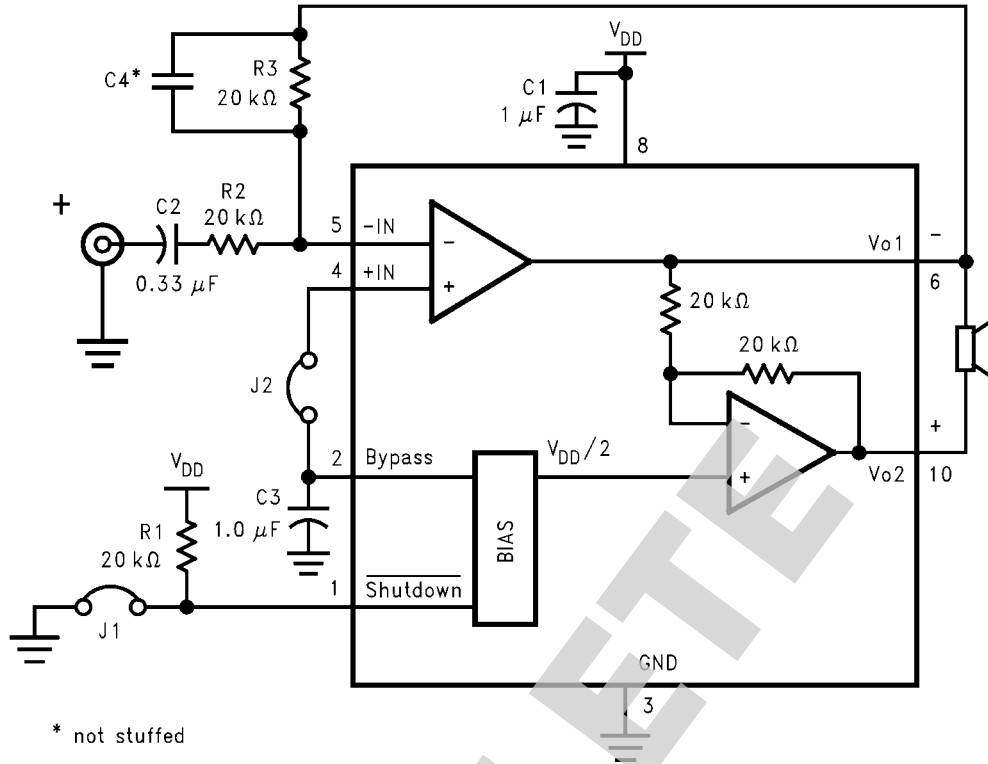
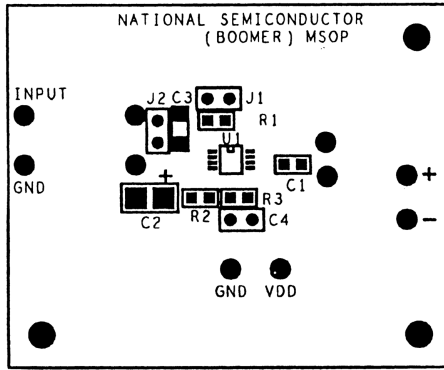


FIGURE 6. REFERENCE DESIGN BOARD and PCB LAYOUT GUIDELINES - MSOP & SO Boards

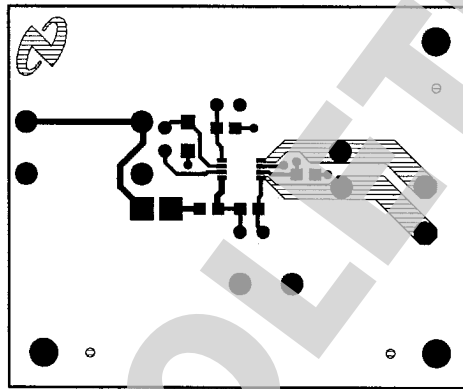
LM4893 MSOP DEMO BOARD ARTWORK

Silk Screen



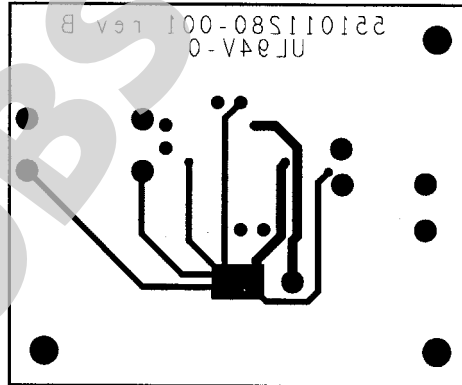
20038065

Top Layer



20038066

Bottom Layer



20038067

**Mono LM4893 Reference Design Boards
Bill of Material for all 3 Demo Boards**

Item	Part Number	Part Description	Qty	Ref Designator
1	551011208-001	LM4893 Mono Reference Design Board	1	
10	482911183-001	LM4893 Audio AMP	1	U1
20	151911207-001	Tant Cap 1uF 16V 10	1	C1
21	151911207-002	Cer Cap 0.39uF 50V Z5U 20% 1210	1	C2
25	152911207-001	Tant Cap 1.0uF 16V 10	1	C3
30	472911207-001	Res 20K Ohm 1/10W 5	3	R1, R2, R3
35	210007039-002	Jumper Header Vertical Mount 2X1 0.100	2	J1, J2

PCB LAYOUT GUIDELINES

This section provides practical guidelines for mixed signal PCB layout that involves various digital/analog power and ground traces. Designers should note that these are only "rule-of-thumb" recommendations and the actual results will depend heavily on the final layout.

General Mixed Signal Layout Recommendations

POWER AND GROUND CIRCUITS

For 2 layer mixed signal design, it is important to isolate the digital power and ground trace paths from the analog power and ground trace paths. Star trace routing techniques (bringing individual traces back to a central point rather than daisy chaining traces together in a serial manner) can have a major impact on low level signal performance. Star trace routing refers to using individual traces to feed power and ground to each circuit or even device. This technique will take require a greater amount of design time but will not increase the final price of the board. The only extra parts required may be some jumpers.

SINGLE-POINT POWER / GROUND CONNECTIONS

The analog power traces should be connected to the digital traces through a single point (link). A "Pi-filter" can be helpful in minimizing high frequency noise coupling between the analog and digital sections. It is further recommended to put digital and analog power traces over the corresponding digital and analog ground traces to minimize noise coupling.

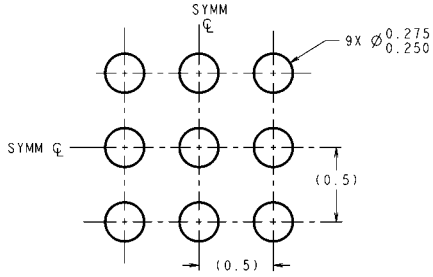
PLACEMENT OF DIGITAL AND ANALOG COMPONENTS

All digital components and high-speed digital signals traces should be located as far away as possible from analog components and circuit traces.

AVOIDING TYPICAL DESIGN / LAYOUT PROBLEMS

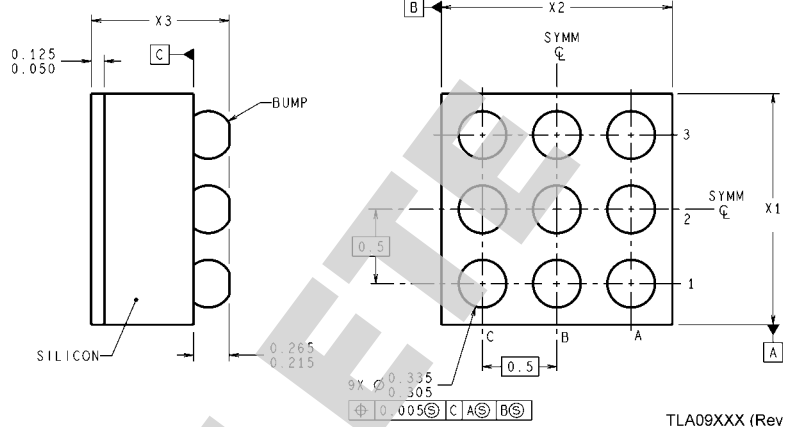
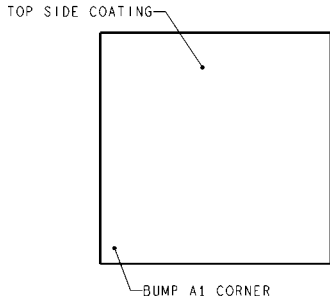
Avoid ground loops or running digital and analog traces parallel to each other (side-by-side) on the same PCB layer. When traces must cross over each other do it at 90 degrees. Running digital and analog traces at 90 degrees to each other from the top to the bottom side as much as possible will minimize capacitive noise coupling and cross talk.

Physical Dimensions inches (millimeters) unless otherwise noted



DIMENSIONS ARE IN MILLIMETERS
DIMENSIONS IN () FOR REFERENCE ONLY

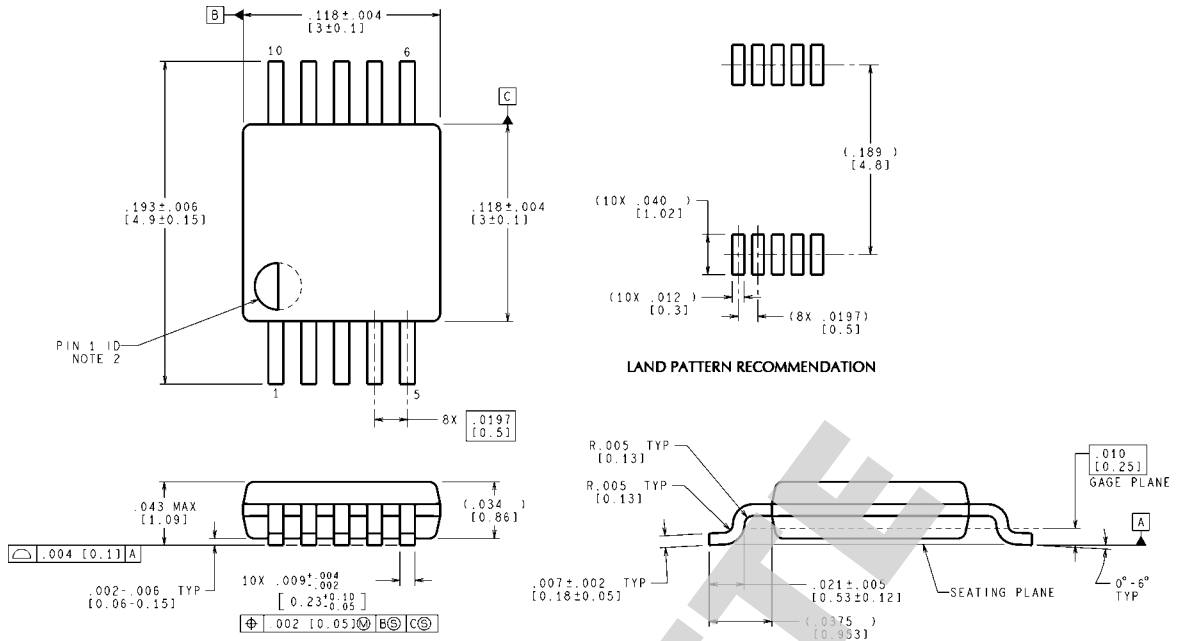
LAND PATTERN RECOMMENDATION



TLA09XXX (Rev C)

9-Bump micro SMD
Order Number LM4893ITL, LM4893ITLX
NS Package Number TLA09AAA
 $X_1 = 1.514 \pm 0.03$ $X_2 = 1.514 \pm 0.03$ $X_3 = 0.60 \pm 0.075$

OBSO



CONTROLLING DIMENSION IS INCH
 VALUES IN [] ARE MILLIMETERS
 DIMENSIONS IN () FOR REFERENCE ONLY

MSOP
Order Number LM4893MM
NS Package Number MUB10A

MUB10A (Rev B)

OBSOLETE

Notes

LM4893

OBSOLETE

Notes

For more National Semiconductor product information and proven design tools, visit the following Web sites at:
www.national.com

Products		Design Support	
Amplifiers	www.national.com/amplifiers	WEBENCH® Tools	www.national.com/webench
Audio	www.national.com/audio	App Notes	www.national.com/appnotes
Clock and Timing	www.national.com/timing	Reference Designs	www.national.com/refdesigns
Data Converters	www.national.com/adc	Samples	www.national.com/samples
Interface	www.national.com/interface	Eval Boards	www.national.com/evalboards
LVDS	www.national.com/lvds	Packaging	www.national.com/packaging
Power Management	www.national.com/power	Green Compliance	www.national.com/quality/green
Switching Regulators	www.national.com/switchers	Distributors	www.national.com/contacts
LDOs	www.national.com/ldo	Quality and Reliability	www.national.com/quality
LED Lighting	www.national.com/led	Feedback/Support	www.national.com/feedback
Voltage References	www.national.com/vref	Design Made Easy	www.national.com/easy
PowerWise® Solutions	www.national.com/powerwise	Applications & Markets	www.national.com/solutions
Serial Digital Interface (SDI)	www.national.com/sdi	Mil/Aero	www.national.com/milaero
Temperature Sensors	www.national.com/tempensors	SolarMagic™	www.national.com/solarmagic
PLL/VCO	www.national.com/wireless	PowerWise® Design University	www.national.com/training

THE CONTENTS OF THIS DOCUMENT ARE PROVIDED IN CONNECTION WITH NATIONAL SEMICONDUCTOR CORPORATION ("NATIONAL") PRODUCTS. NATIONAL MAKES NO REPRESENTATIONS OR WARRANTIES WITH RESPECT TO THE ACCURACY OR COMPLETENESS OF THE CONTENTS OF THIS PUBLICATION AND RESERVES THE RIGHT TO MAKE CHANGES TO SPECIFICATIONS AND PRODUCT DESCRIPTIONS AT ANY TIME WITHOUT NOTICE. NO LICENSE, WHETHER EXPRESS, IMPLIED, ARISING BY ESTOPPEL OR OTHERWISE, TO ANY INTELLECTUAL PROPERTY RIGHTS IS GRANTED BY THIS DOCUMENT.

TESTING AND OTHER QUALITY CONTROLS ARE USED TO THE EXTENT NATIONAL DEEMS NECESSARY TO SUPPORT NATIONAL'S PRODUCT WARRANTY. EXCEPT WHERE MANDATED BY GOVERNMENT REQUIREMENTS, TESTING OF ALL PARAMETERS OF EACH PRODUCT IS NOT NECESSARILY PERFORMED. NATIONAL ASSUMES NO LIABILITY FOR APPLICATIONS ASSISTANCE OR BUYER PRODUCT DESIGN. BUYERS ARE RESPONSIBLE FOR THEIR PRODUCTS AND APPLICATIONS USING NATIONAL COMPONENTS. PRIOR TO USING OR DISTRIBUTING ANY PRODUCTS THAT INCLUDE NATIONAL COMPONENTS, BUYERS SHOULD PROVIDE ADEQUATE DESIGN, TESTING AND OPERATING SAFEGUARDS.

EXCEPT AS PROVIDED IN NATIONAL'S TERMS AND CONDITIONS OF SALE FOR SUCH PRODUCTS, NATIONAL ASSUMES NO LIABILITY WHATSOEVER, AND NATIONAL DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY RELATING TO THE SALE AND/OR USE OF NATIONAL PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS PRIOR WRITTEN APPROVAL OF THE CHIEF EXECUTIVE OFFICER AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

Life support devices or systems are devices which (a) are intended for surgical implant into the body, or (b) support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in a significant injury to the user. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system or to affect its safety or effectiveness.

National Semiconductor and the National Semiconductor logo are registered trademarks of National Semiconductor Corporation. All other brand or product names may be trademarks or registered trademarks of their respective holders.

Copyright© 2011 National Semiconductor Corporation

For the most current product information visit us at www.national.com



www.national.com

**National Semiconductor
Americas Technical
Support Center**

Email: support@nsc.com
Tel: 1-800-272-9959

**National Semiconductor Europe
Technical Support Center**

Email: europe.support@nsc.com

**National Semiconductor Asia
Pacific Technical Support Center**

Email: ap.support@nsc.com

**National Semiconductor Japan
Technical Support Center**

Email: jpn.feedback@nsc.com

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Mobile Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Transportation and Automotive	www.ti.com/automotive
Video and Imaging	www.ti.com/video

TI E2E Community Home Page

e2e.ti.com

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2011, Texas Instruments Incorporated